

HD74LVC244A

Octal Buffers / Line Drivers with 3-state Outputs

REJ03D0352-0400Z (Previous ADE-205-110B (Z)) Rev.4.00 Jul. 27, 2004

Description

The HD74LVC244A has eight line drivers with three state outputs in a 20 pin package. This device is a non inverting buffer and has two active low enables ($1\overline{G}$ and $2\overline{G}$). Each enable independently controls four buffers. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs V_{OUT} (Max.) = 5.5 V (@ V_{CC} = 0 V or output off state)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High output current ± 24 mA (@V_{CC} = 3.0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVC244AFPEL	SOP-20 pin (JEITA)	FP-20DAV	FP	EL (2,000 pcs/reel)
HD74LVC244ATELL	TSSOP-20 pin	TTP-20DAV	T	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

Function Table

In	nı	ıte
111	μu	ເເວ

G	A	Output Y
Н	X	Z
L	Н	Н
L	L	L

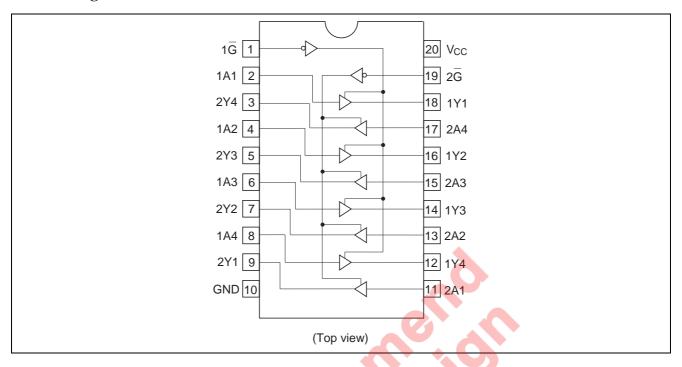
H: High level

L: Low level

X: Immaterial

Z: High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	Vcc	-0.5 to 6.0	V	
Input diode current	I _{IK}	-50	mA	$V_{I} = -0.5 \text{ V}$
Input voltage	VI	-0.5 to 6.0	V	
Output diode current	I _{OK}	-50	mA	$V_{O} = -0.5 \text{ V}$
		50	<u> </u>	$V_O = V_{CC} + 0.5 \text{ V}$
Output voltage	Vo	-0.5 to V_{CC} +0.5	V	Output "H" or "L"
		-0.5 to 6.0	_	Output "Z" V _{CC} :OFF
Output current	I _O	±50	mA	
V _{CC} , GND current / pin	I _{CC} or I _{GND}	100	mA	
Storage temperature	Tstg	-65 to 150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	1.5 to 5.5	V	Data retention
		2.0 to 5.5		At operation
Input / output voltage	Vı	0 to 5.5	V	G , A
	Vo	0 to V _{CC}	V	Output "H" or "L"
		0 to 5.5		Output "Z" or V _{CC} :OFF
Operating temperature	Та	-40 to 85	°C	
Output current	I _{OH}	-12	mA	V _{CC} = 2.7 V
		-24 ^{*2}		V _{CC} = 3.0 V to 5.5 V
	I _{OL}	12	mA	V _{CC} = 2.7 V
		24 ^{*2}		V _{CC} = 3.0 V to 5.5 V
Input rise / fall time *1	t _r , t _f	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

2. Duty cycle ≤ 50%

Electrical Characteristics

		Ta = −40 to 85°C				
Item	Symbol	V _{CC} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.7 to 3.6	2.0		V	
		4.5 to 5.5	V _{CC} ×0.7			
	V _{IL}	2.7 to 3.6	-	0.8	V	
		4.5 to 5.5	40	$V_{CC}\times0.3$		
Output voltage	V _{OH}	2.7 to 5.5	V _{CC} -0.2	_	V	$I_{OH} = -100 \mu A$
		2.7	2.2	7	_	$I_{OH} = -12 \text{ mA}$
		3.0	2.4	_	_	
	A	3.0	2.2	_	_	$I_{OH} = -24 \text{ mA}$
		4.5	3.8	_		
	V _{OL}	2.7 to 5.5	_	0.2	V	$I_{OL} = 100 \mu A$
		2.7	_	0.4	_	I _{OL} = 12 mA
		3.0	_	0.55	_	I _{OL} = 24 mA
		4.5	_	0.55		
Input current	I _{IN}	0 to 5.5	_	±5.0	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state output current	l _{OZ}	2.7 to 5.5	_	±5.0	μΑ	$V_{IN} = V_{CC}$, GND,
						$V_{OUT} = 5.5 \text{ V or GND}$
Output leak current	I_{OFF}	0	_	20	μΑ	$V_{IN} / V_{OUT} = 5.5 V$
Quiescent supply current	I _{CC}	2.7 to 3.6	_	±10	μΑ	$V_{IN} / V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$
		2.7 to 5.5	_	10		V _{IN} = V _{CC} or GND
	ΔI_{CC}	3.0 to 3.6	_	500	μA	V_{IN} = one input at $(V_{CC}-0.6)V$,
						other inputs at V _{CC} or GND

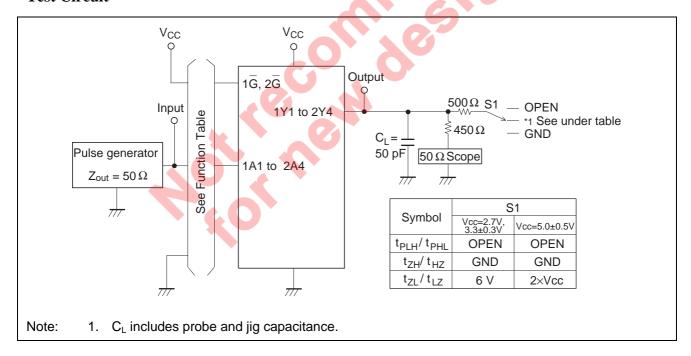
Switching Characteristics

			,	Ta = -40 to	85°C		From	То
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	2.7	_	_	7.5	ns	А	Υ
	t_{PHL}	3.3±0.3	1.5	_	6.5			
		5.0±0.5	_	_	5.0			
Output enable time	t_{ZH}	2.7	_	_	9.0	ns	G	Υ
	t_{ZL}	3.3±0.3	1.5	_	8.0			
		5.0±0.5	_	_	6.5			
Output disable time	t _{ZH}	2.7	_	_	8.0	ns	G	Υ
	t_{LZ}	3.3±0.3	1.5	_	7.0			
		5.0±0.5	_	_	6.0			
Between output pins skew	t _{OSLH}	2.7	_	_	_	ns		
*1	t_{OSHL}	3.3±0.3	_	_	1.0			
		5.0±0.5	_	_	1.0			
Input capacitance	C _{IN}	2.7	_	3.0	_	pF		
Output capacitance	Co	2.7	_	15.0		pF	_	

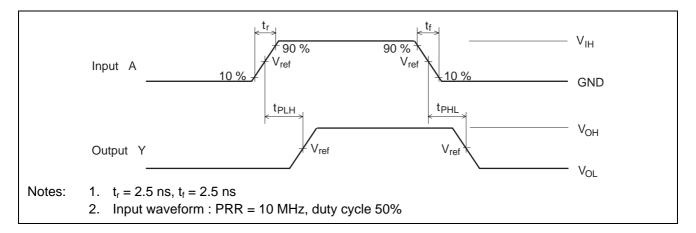
Note: 1. This parameter is characterized but not tested.

 $tos_{LH} = |t_{PLHm} - t_{PLHn}|, tos_{HL} = |t_{PHLm} - t_{PHLn}|$

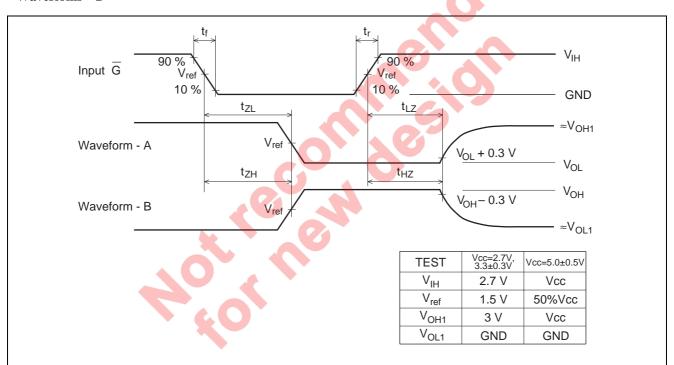
Test Circuit



Waveforms - 1



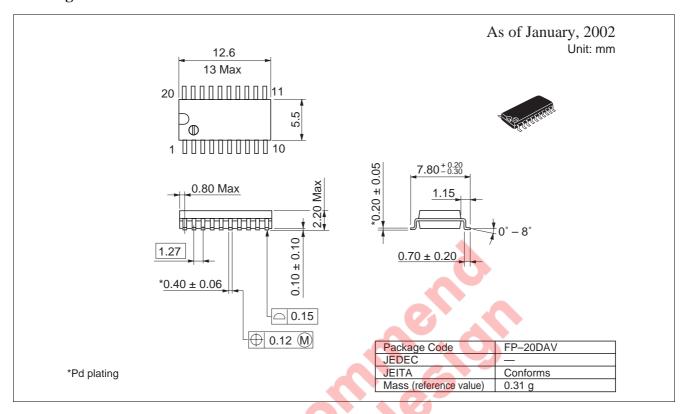
Waveforms - 2

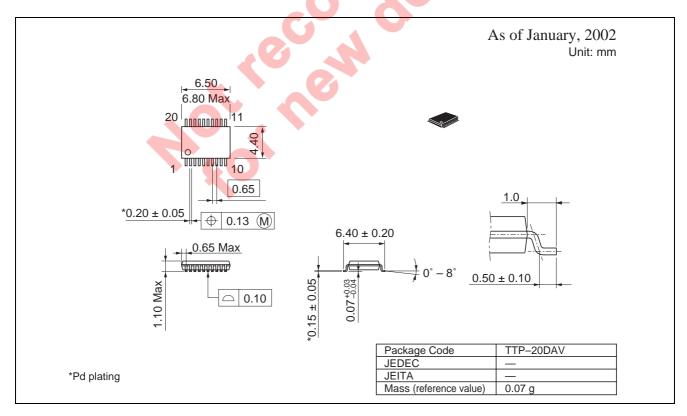


Notes:

- 1. $t_r = 2.5 \text{ ns}, t_f = 2.5 \text{ ns}$
- 2. Input waveform: PRR = 10 MHz, duty cycle 50%
- 3. Waveform A shows input conditions such that the output is "L" level when enable by the output control.
- 4. Waveform B shows input conditions such that the output is "H" level when enable by the output control.

Package Dimensions





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